

KSC1730

TV VHF, UHF Tuner Oscillator

- High Current Gain Bandwidth Product : f_T=1100MHz
- Output Capacitance : C_{OB}=1.5pF (MAX.)



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	30	V
V _{CEO}	Collector-Emitter Voltage	15	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current	50	mA
P _C	Collector Power Dissipation	250	mW
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_{C}=10\mu A, I_{E}=0$	30			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C=5mA$, $I_B=0$	15			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E=10\mu A, I_C=0$	5			V
I _{CBO}	Collector Cut-off Current	$V_{CB}=12V$, $I_{E}=0$			0.1	μΑ
h _{FE}	DC Current Gain	V _{CE} =10V, I _C =5mA	40		240	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =10mA, I _B =1mA			0.5	V
f _T	Current Gain Bandwidth Product	V _{CE} =10V, I _C =5mA	800	1100		MHz
C _{ob}	Output Capacitance	V _{CB} =10V, I _E =0, f=1MHz			1.5	pF
C _{c-rbb'}	Collector-Base Time Constant	V _{CE} =10V, I _E =5mA f=31.9MHz		10	20	ps

h_{FE} Classification

Classification	R	0	Υ
h _{FE}	40 ~ 80	70 ~ 140	120 ~ 240

Typical Characteristics

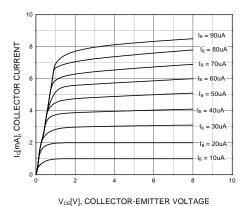
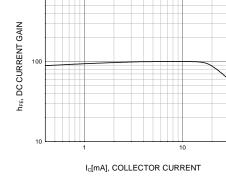


Figure 1. Static Characteristic



1000

Figure 2. DC current Gain

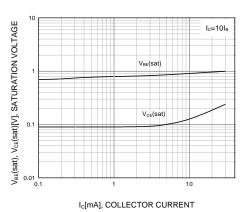


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

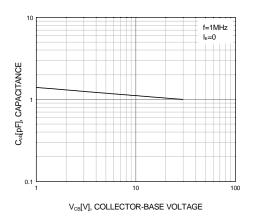


Figure 4. Collector Output Capacitance

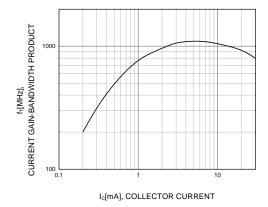


Figure 5. Current Gain Bandwidth Product

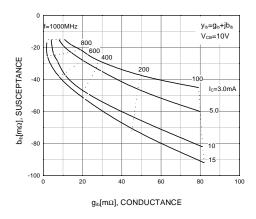


Figure 6. Input Admittance (yib) vs. Frequency

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Typical Characteristics (Continued)

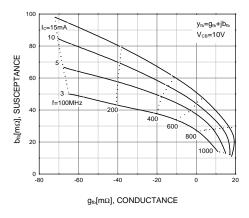


Figure 7. Forward Transfer Admittance (yfb) vs. Frequency

Figure 8. Output Admittance (yob) vs. Frequency

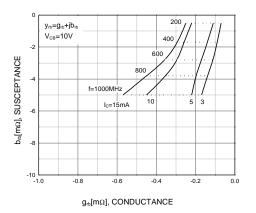
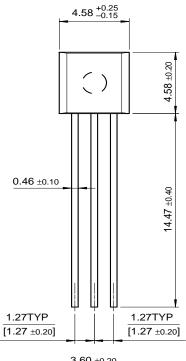


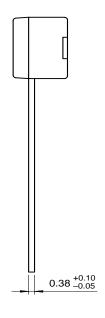
Figure 9. Reverse Transfer Admittance (yrb) vs. Frequency

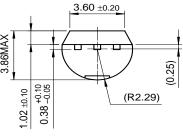
KSC1730

Package Demensions

TO-92







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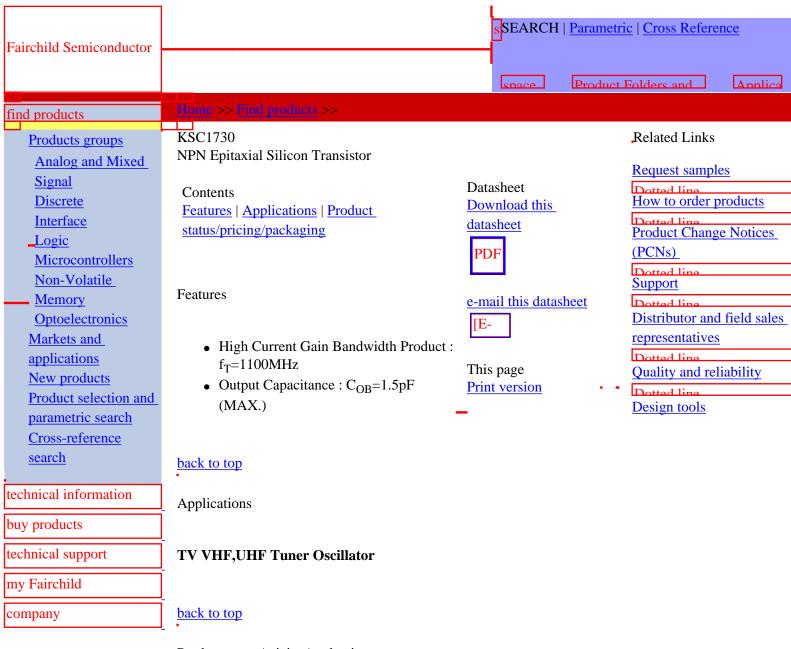
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Product status/pricing/packaging

Product	Product status	Pricing*	Package type	Leads	Packing method
KSC1730OBU	Full Production	\$0.053	<u>TO-92</u>	3	BULK
KSC1730YTA	Full Production	\$0.053	<u>TO-92</u>	3	TAPE REEL
KSC1730YBU	Full Production	\$0.053	<u>TO-92</u>	3	BULK
KSC1730OTA	Full Production	\$0.053	<u>TO-92</u>	3	TAPE REEL

^{* 1,000} piece Budgetary Pricing

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